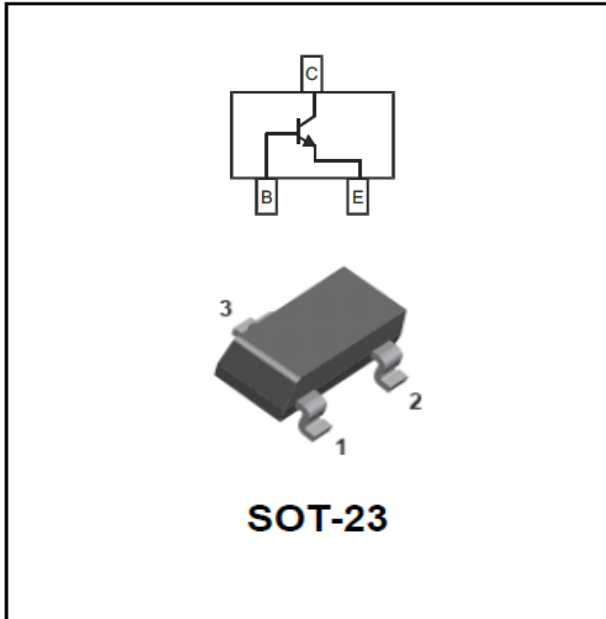


NPN Transistor



Features

- Epoxy meets UL-94 V-0 flammability rating
- Halogen free available upon request by adding suffix "HF"
- Moisture Sensitivity Level 1
- High Conductance
- Surface mount package ideally Suited for Automatic Insertion

Mechanical Data

- **Package:** SOT-23
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Marking:** 3D

■ Maximum Ratings (Ta=25°C unless otherwise noted)

Item	Symbol	Unit	Value
Collector-Base Voltage	V_{CBO}	V	400
Collector-Emitter Voltage	V_{CEO}	V	400
Emitter-Base Voltage	V_{EBO}	V	6
Collector Current	I_C	mA	200
Collector Power Dissipation	P_C	mW	350
Operation Junction Temperature	T_j	°C	150
Storage Temperature	T_{stg}	°C	-55 to +150



■ Electrical Characteristics (Ta=25°C unless otherwise noted)

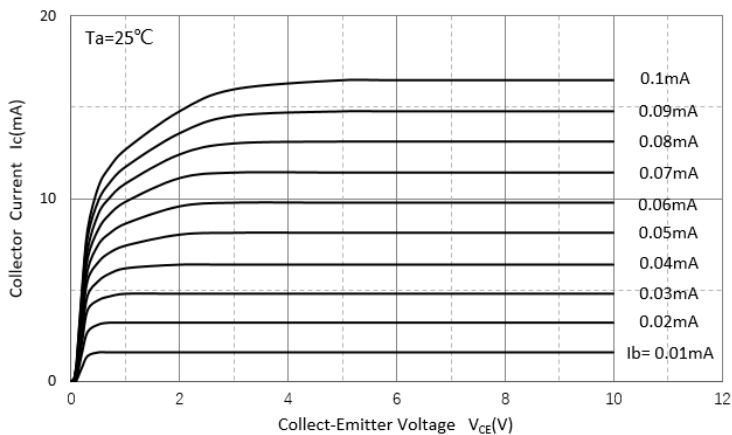
Item	Symbol	Unit	Conditions	Min	Typ	Max
Collector-base breakdown voltage	V_{CBO}	V	$I_C=100\mu A, I_E=0$	400		
Collector-emitter breakdown voltage	V_{CEO^*}	V	$I_C=1mA, I_B=0$	400		
Emitter-base breakdown voltage	V_{EBO}	V	$I_E=10\mu A, I_C=0$	6		
Collector-base cut-off current	I_{CBO}	nA	$V_{CB}=400V, I_E=0$			100
Emitter-base cut-off current	I_{EBO}	nA	$V_{EB}=4V, I_C=0$			100
DC current gain	h_{FE}		$V_{CE}=10V, I_C=1mA$	40		
	h_{FE}		$V_{CE}=10V, I_C=10mA$	50		200
	h_{FE}		$V_{CE}=10V, I_C=50mA$	45		
	h_{FE}		$V_{CE}=10V, I_C=100mA$	40		
Collector-emitter saturation voltage	$V_{CE(sat)}$	V	$I_C=10mA, I_B=1mA$			0.5
Collector-emitter saturation voltage	$V_{CE(sat)}$	V	$I_C=50mA, I_B=5mA$			0.75
Base-emitter saturation voltage	$V_{BE(sat)}$	V	$I_C=10mA, I_B=1mA$			0.75

■ Ordering Information (Example)

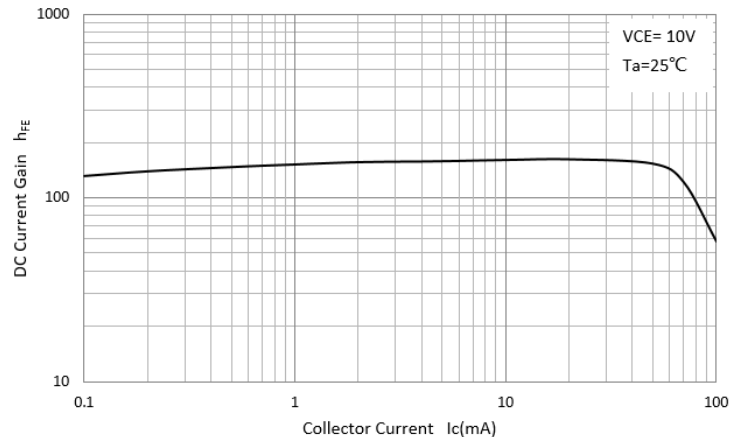
PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MMBTA44	F2	Approximate 0.008	3000	30000	120000	7" reel

■ Characteristics(Typical)

Static Characteristic

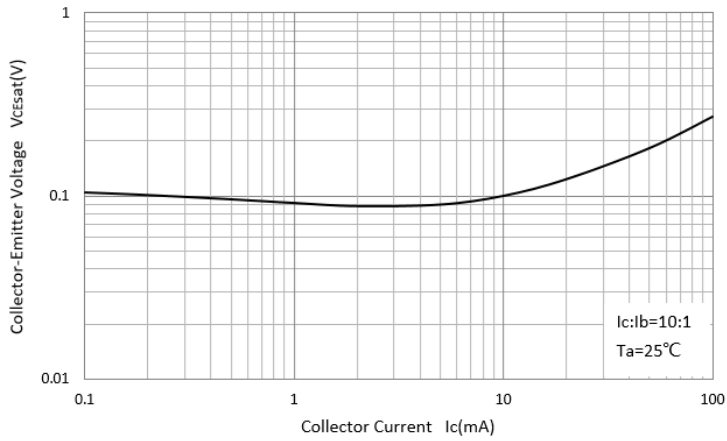


DC Current Gain

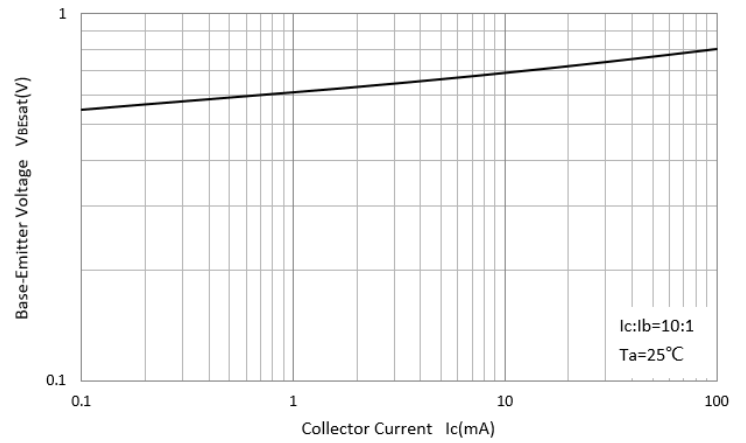




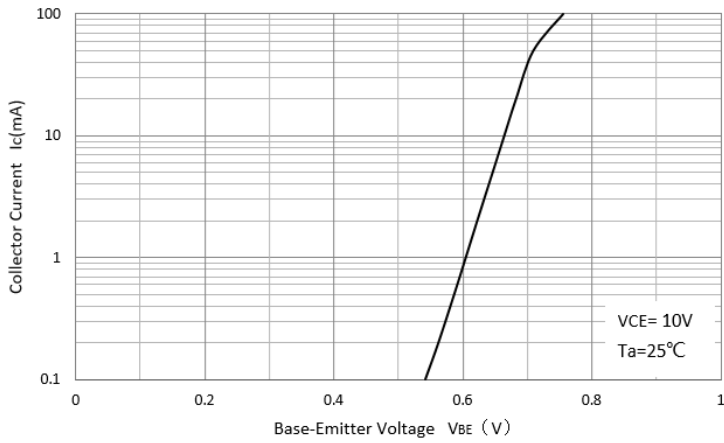
Collector-Emitter Saturation Voltage



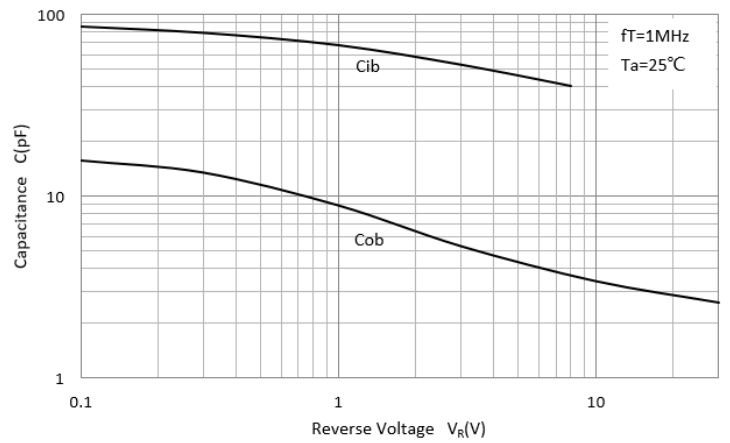
Base-Emitter Saturation Voltage



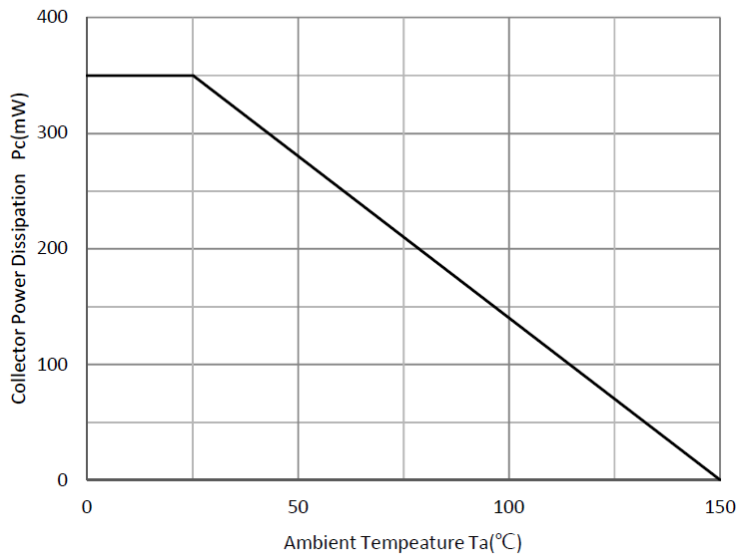
Base-Emitter On Voltage



$C_{ob}/C_{ib}-V_{CB}/V_{EB}$

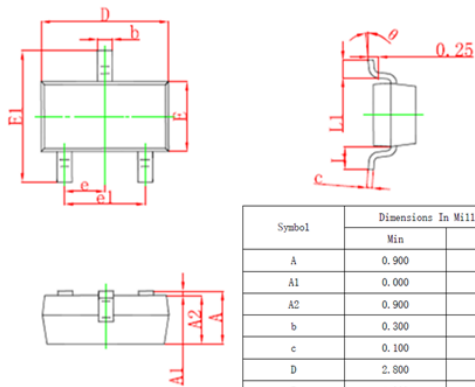


Collector Power Derating Curve



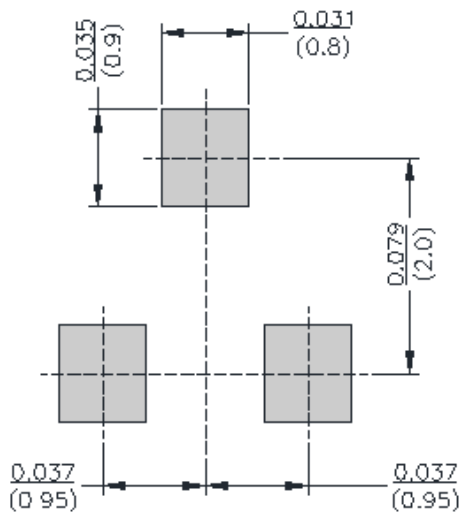


■SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550REF		0.022REF	
L1	0.300	0.500	0.012	0.020
ø	0°	8°	0°	8°

■SOT-23 Suggested Pad Layout





Disclaimer

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